



SYNCHRONOUS BUCK CONTROLLER WITH 4-BIT VID INTERFACE FOR SMART-REFLEX™ DSPs

FEATURES

- Input Voltage Range: 4.5 V to 14 V
- 4-Bit Dynamic VID-On-The-Fly Support
- VID Programmable Output Voltage with Programmable Transition Rate
- Fixed Switching Frequency of 520 kHz
- Selectable Low-Side (Three Settings) and Fixed High-Side Thermally Compensated Overcurrent Protection
- Power Good Indicator
- Internal 5-V Regulator
- Voltage Mode Control
- Internally Fixed 5.5-ms Soft-Start Time
- Pre-Bias Output Safe
- Thermal Shutdown at 140°C
- 16-Pin QFN Package

APPLICATIONS

- Smart-Reflex™ DSPs
- POL Modules
- Telecom

CONTENTS

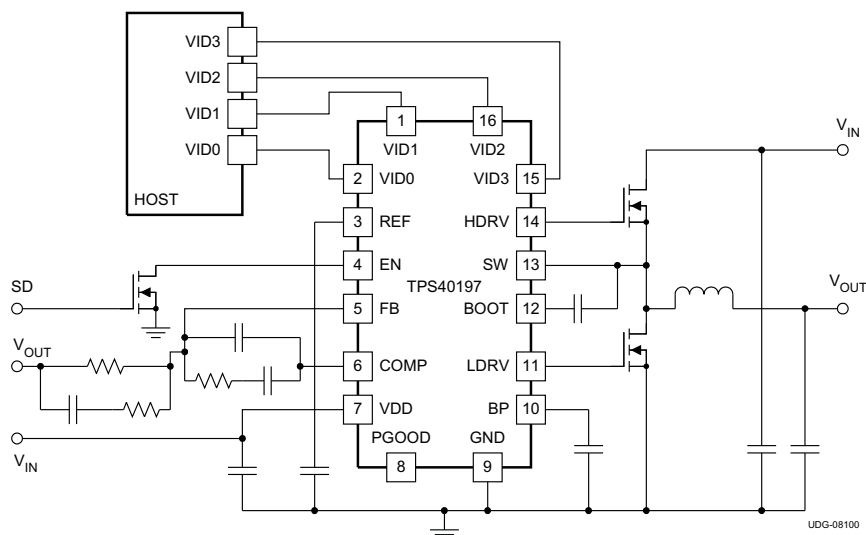
Device Ratings	2
Electrical Characteristics	4
Typical Characteristics	6
Device Information	10
Application Information	12
Design Example	18
Additional References	20

DESCRIPTION

The TPS40197 is a synchronous buck controller that operates from 4.5 V to 14 V input supply nominally. The controller implements voltage-mode control architecture with the switching frequency fixed at 520 kHz. The higher switching frequency facilitates the use of smaller inductor and output capacitors, thereby providing a compact power-supply solution. An adaptive anti-cross conduction scheme is used to prevent shoot through current in the power FETs.

The TPS40197 integrates the PWM control and 4-bit VID interface in a single chip to allow seamless on-the-fly VID changes with programmable transition rate. It provides a simple power solution for Smart-Reflex™ DSP cores.

TYPICAL APPLICATION CIRCUIT



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

SMART-REFLEX, Smart-Reflex, PowerPAD are trademarks of Texas Instruments.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of the Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

Copyright © 2008–2012, Texas Instruments Incorporated



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

DESCRIPTION CONTINUED

Short circuit detection is done by sensing the voltage drop across the low-side FET when it is on and comparing it with a user selected threshold of 100 mV, 200 mV or 280 mV. The threshold is set with a single external resistor connected from COMP to GND. This resistor is sensed at startup and the selected threshold is latched. Pulse by pulse limiting (to prevent current runaway) is provided by sensing the voltage across the high-side FET when it is on and terminating the cycle when the voltage drop rises above a fixed threshold of 550 mV. When the controller senses an output short circuit, both FETs are turned off and a timeout period is observed before attempting to restart. This provides limited power dissipation in the event of a sustained fault.

ORDERING INFORMATION⁽¹⁾

T _A	PACKAGE	ORDERING PART NUMBER	PINS	OUTPUT SUPPLY	MINIMUM ORDER QUANTITY
–40°C to 85°C	Plastic Quad Flatpack	TPS40197RGYT	16	Tube	250
		TPS40197RGYR		Tape-and-Reel	3000

(1) For the most current package and ordering information, see the *Package Option Addendum* at the end of this document, or see the TI website at www.ti.com.

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

		VALUE	UNIT
Input voltage range	VDD, EN	–0.3 to 20	V
	SW	–5 to 25	
	BOOT, HDRV	–0.3 to 30	
	BOOT–SW, HDRV–SW	–0.3 to 6	
	FB, BP, LDRV, PGOOD, REF	–0.3 to 6	
Output voltage range	COMP	–0.3 to 3.5	V
	VID0, VID1, VID2, VID3	–0.3 to 2	
Operating junction temperature range, T _J		–40 to 150	°C
Storage temperature, T _{st}		–55 to 150	°C

(1) Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under *recommended operating conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

RECOMMENDED OPERATING CONDITIONS

over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
Supply voltage	VDD	4.5	14	V
Operating junction temperature, T _J		–40	125	°C

PACKAGE DISSIPATION RATINGS

PACKAGE	AIRFLOW (LFM)	R _{θJA} High-K Board ⁽¹⁾ (°C/W)	Power Rating (W) T _A = 25°C	Power Rating (W) T _A = 85°C
16-Pin Plastic Quad Flatpack (RGY)	0 (Natural Convection)	49.2	2.0	0.81
	200	41.2	2.4	0.97
	400	37.7	2.6	1.00

(1) Ratings based on JEDEC High Thermal Conductivity (High K) Board. For more information on the test method, see TI Technical Brief SZZA017.

ELECTROSTATIC DISCHARGE (ESD) PROTECTION

	MIN	TYP	MAX	UNIT
Human body model (HBM)		2500		V
Charge device model (CDM)		1500		

ELECTRICAL CHARACTERISTICS

–40°C ≤ T_J ≤ 85°C, V_{VDD} = 12 V, all parameters at zero power dissipation (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
VOLTAGE REFERENCE AND VID						
V _{FB}	FB input voltage	0.9 V ≤ V _{VID} ≤ 1.2 V, 0°C ≤ T _J ≤ 85°C	−0.5%		0.5%	V _{VID}
		0.9 V ≤ V _{VID} ≤ 1.2 V, −40°C ≤ T _J ≤ 85°C	−1.0%		1.0%	
I _{VID}	VID pull-up current		50	80	120	μA
V _{VID}	VID pull-up voltage		1.60	1.68	1.78	V
t _{ANTI-SKEW (1)}	Anti-skew filtering time		300	550	750	ns
V _{VIDH}	VID high-level input voltage		0.8	1.0	1.3	V
V _{VIDL}	VID low-level input voltage		0.30	0.55	0.70	V
I _{REF}	REF source/sink current		400	650	850	μA
INPUT SUPPLY						
V _{VDD}	Normal input supply voltage range		4.5		14.0	V
I _{VDD}	Operating current	V _{ENABLE} = 3 V		2.5	4.5	mA
		V _{ENABLE} = 0.6 V		45	70	μA
SOFT-START						
t _{SS}	Soft-start time		3.3	5.5	7.0	ms
t _{SSDLY}	Soft-start delay time		1.3	2.3	4.0	
t _{REG}	Time to regulation		5.0	8.0	11.0	
ON-BOARD REGULATOR						
V _{BP}	Output voltage	V _{VDD} > 6 V, I _{BP} ≤ 10 mA	5.1	5.3	5.5	V
V _{DO}	Regulator dropout voltage (V _{VDD} −V _{BP})	V _{VDD} >5 V, I _{BP} ≤ 25 mA		350	550	mV
I _{SC}	Regulator current limit threshold		50			mA
I _{BP}	Average current				50	
OSCILLATOR						
f _{SW}	Switching frequency		420	520	600	kHz
V _{RAMP} ⁽¹⁾	Ramp amplitude			1		V
PWM						
D _{MAX} ⁽¹⁾	Maximum duty cycle		85%			ns
t _{ON(min)} ⁽¹⁾	Minimum controllable pulse				110	
t _{DEAD}	Output driver dead time	HDRV off to LDRV on		50		
		LDRV off to HDRV on		25		
ERROR AMPLIFIER						
G _{BWP} ⁽¹⁾	Gain bandwidth product		7	10		MHz
A _{OL} ⁽¹⁾	Open loop gain		60			dB
I _{IB}	Input bias current (current out of FB pin)				100	nA
I _{EAOP}	Output source current	V _{FB} = 0 V	1			mA
I _{EAOM}	Output sink current	V _{FB} = 2 V	1			
UNDERVOLTAGE LOCKOUT						
V _{UVLO}	Turn-on voltage		3.9	4.2	4.4	V
UVLO _{HYST}	Hysteresis		700	850	1000	mV
SHUTDOWN						
V _{IH}	High-level input voltage, ENABLE			1.9	3.0	V
V _{IL}	Low-level input voltage, ENABLE		0.6	1.2		

(1) Specified by design. Not production tested.

ELECTRICAL CHARACTERISTICS (continued)

–40°C ≤ T_J ≤ 85°C, V_{VDD} = 12 V, all parameters at zero power dissipation (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
OUTPUT DRIVERS						
R _{HDHI}	High-side driver pull-up resistance	(V _{BOOT} – V _{SW}) - 4.5 V, I _{HDR} V = – 100 mA		3.0	6.0	Ω
R _{HDLO}	High-side driver pull-down resistance	(V _{BOOT} – V _{SW}) - 4.5 V, I _{HDR} V = 100 mA		1.5	3.0	
R _{LDHI}	Low-side driver pull-up resistance	I _{LDR} V = –100 mA		2.5	5.0	
R _{LDLO}	Low-side driver pull-down resistance	I _{LDR} V = 100 mA		0.8	1.5	
t _{HRISE} ⁽²⁾	High-side driver rise time	C _{LOAD} = 1 nF		15	35	ns
t _{HFALL} ⁽²⁾	High-side driver fall time			10	25	
t _{LRISE} ⁽²⁾	Low-side driver rise time			15	35	
t _{LFALL} ⁽²⁾	Low-side driver fall time			10	25	
SHORT CIRCUIT PROTECTION						
t _{PSS(min)} ⁽²⁾	Minimum pulse time during short circuit			250		ns
t _{BLNK} ⁽²⁾	Switch leading-edge blanking pulse time		60	90	120	
t _{OFF}	Off-time between restart attempts		30	50		ms
V _{ILIM}	Short circuit comparator threshold voltage	R _{COMP(GND)} = OPEN, T _J = 25°C	160	200	240	mV
		R _{COMP(GND)} = 4 kΩ, T _J = 25°C	80	100	120	
		R _{COMP(GND)} = 12 kΩ, T _J = 25°C	228	280	342	
V _{ILIMH}	Short circuit threshold voltage on high-side MOSFET	T _J = 25°C	400	550	650	
POWER GOOD						
V _{OV}	Feedback voltage limit for powergood		106%	110%	114%	VID
V _{UV}			86%	90%	94%	
V _{PG_HYST}	Powergood hysteresis voltage at FB pin		10	30	70	mV
R _{PGD}	Pull-down resistance of PGD pin	V _{FB} < 90% V _{VID} mV or V _{FB} > 110% V _{VID}		7	50	Ω
I _{PDGLK}	Leakage current	90% V _{VID} ≤ V _{FB} ≤ 100% V _{VID} , V _{PGOOD} = 5 V		7	12	μA
BOOT DIODE						
V _{DFWD}		I _{BOOT} = 5 mA	0.5	0.8	1.2	V
THERMAL SHUTDOWN						
T _{JSD} ⁽²⁾	Junction shutdown temperature			140		°C
T _{JSDH} ⁽²⁾	Hysteresis			20		

(2) Specified by design. Not production tested.

TYPICAL CHARACTERISTICS

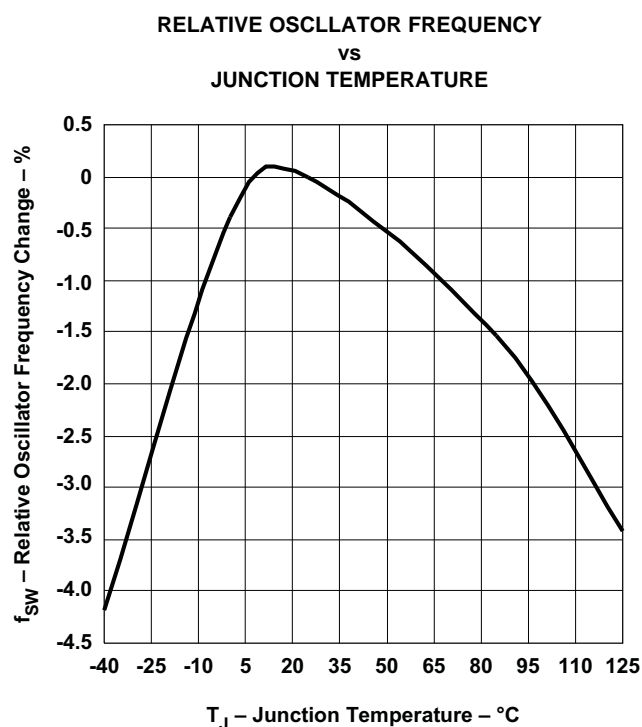


Figure 1.

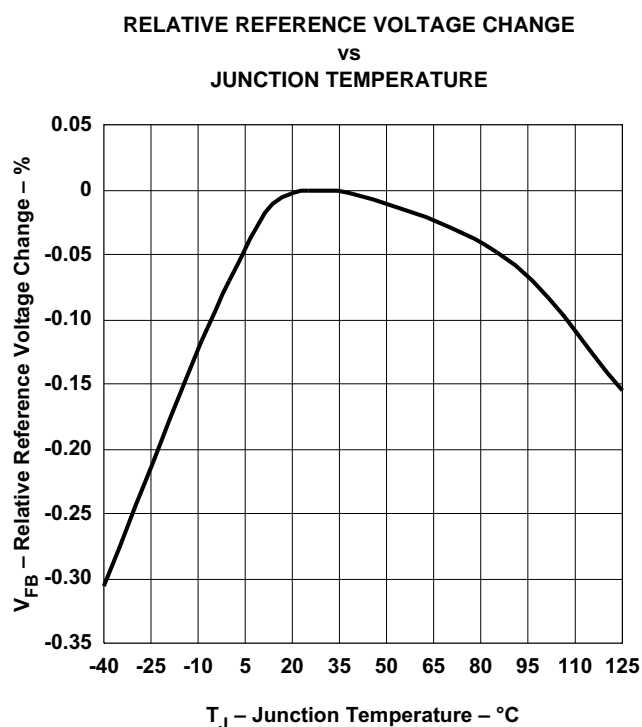


Figure 2.

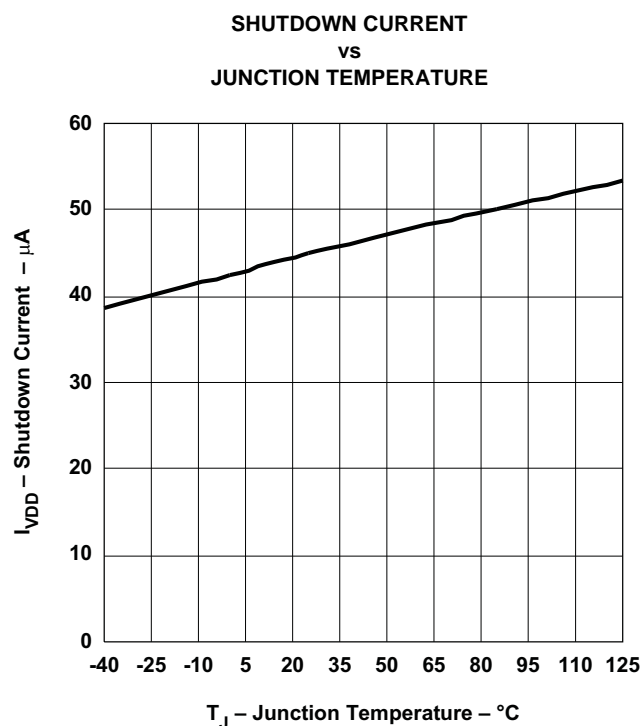


Figure 3.

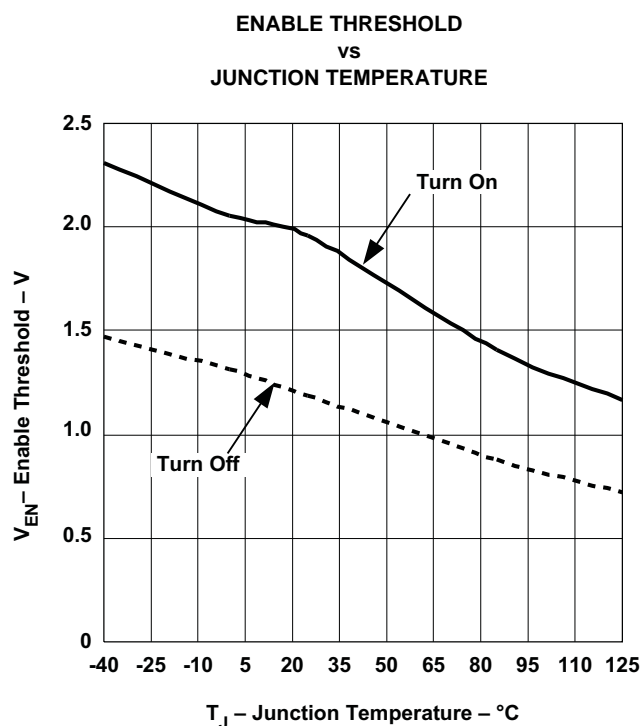


Figure 4.

TYPICAL CHARACTERISTICS (continued)

SOFT START TIME
vs
JUNCTION TEMPERATURE

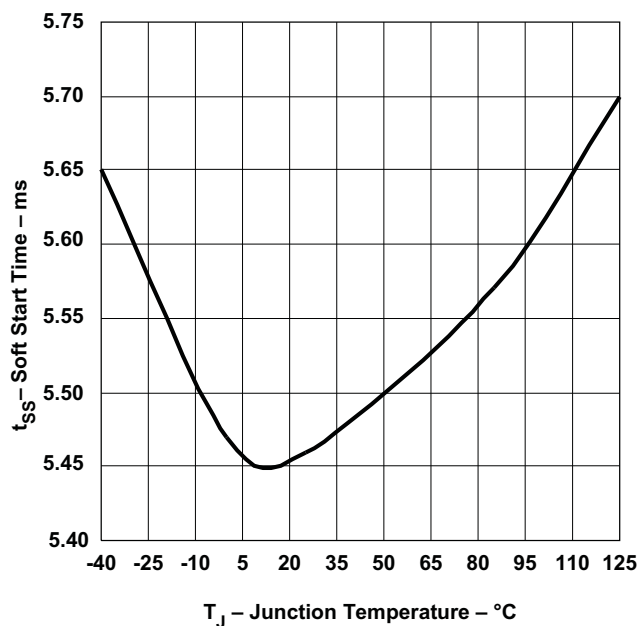


Figure 5.

LOW-SIDE MOSFET CURRENT LIMIT THRESHOLD
vs
JUNCTION TEMPERATURE

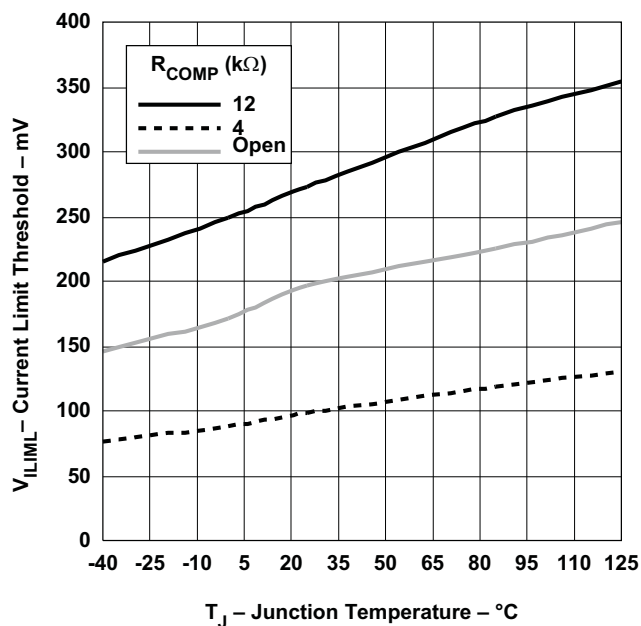


Figure 6.

HIGH-SIDE MOSFET CURRENT LIMIT THRESHOLD
vs
JUNCTION TEMPERATURE

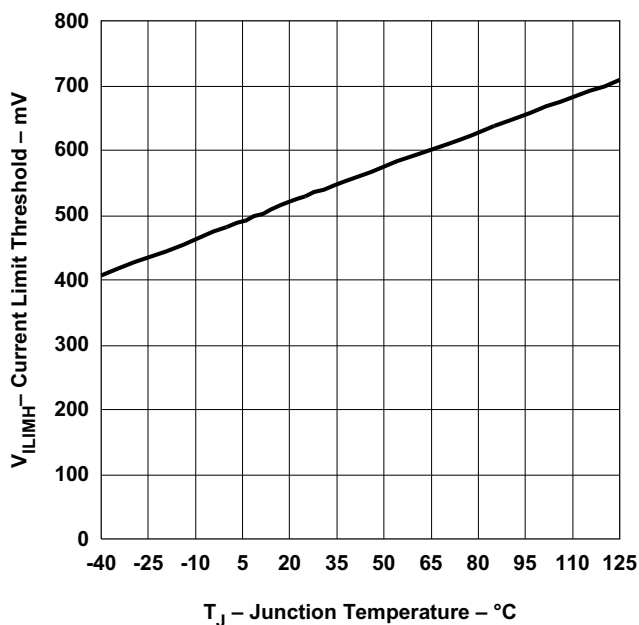


Figure 7.

TOTAL TIME-TO-REGULATION
vs
JUNCTION TEMPERATURE

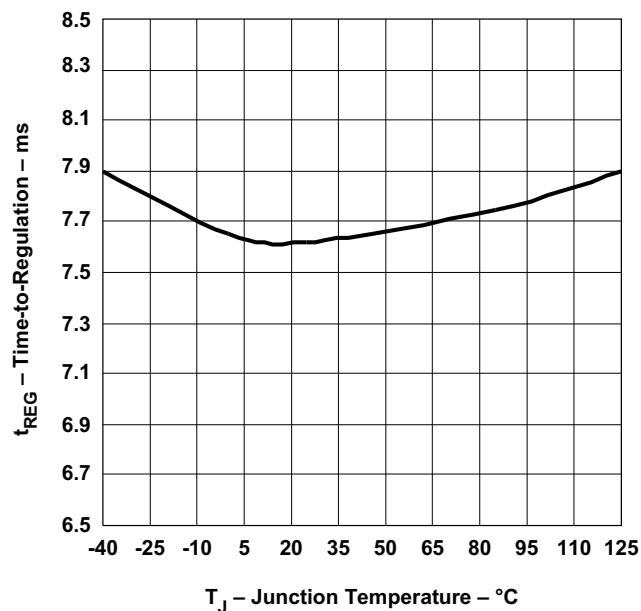


Figure 8.

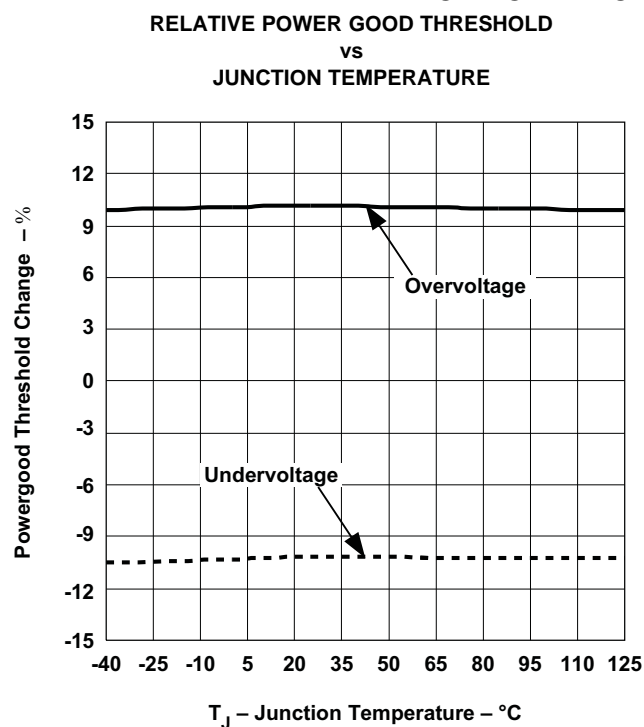
TYPICAL CHARACTERISTICS (continued)

Figure 9.

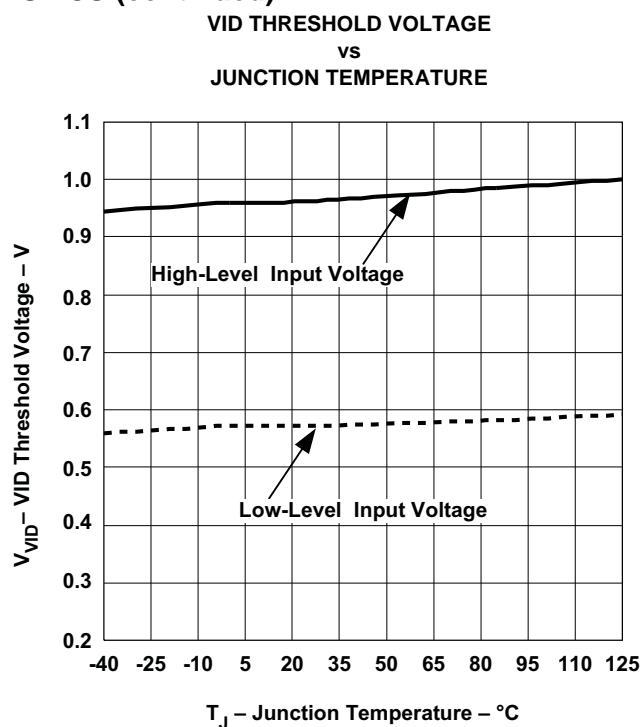


Figure 10.

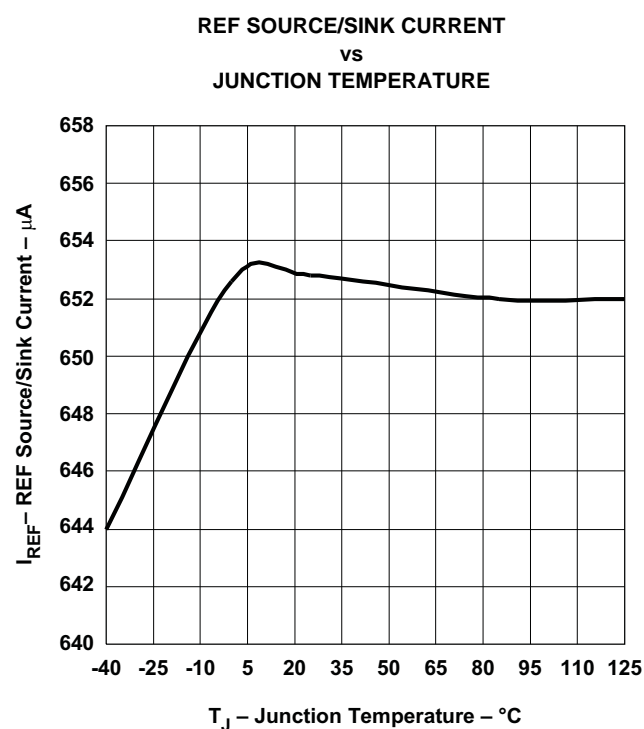


Figure 11.

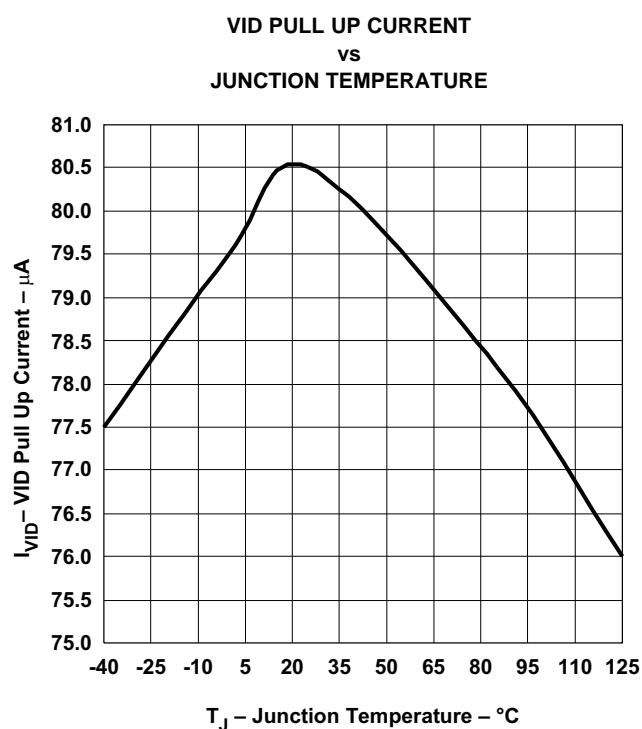


Figure 12.

TYPICAL CHARACTERISTICS (continued)
RELATIVE OVERCURRENT TRIP POINT
vs
FREEWHEEL TIME

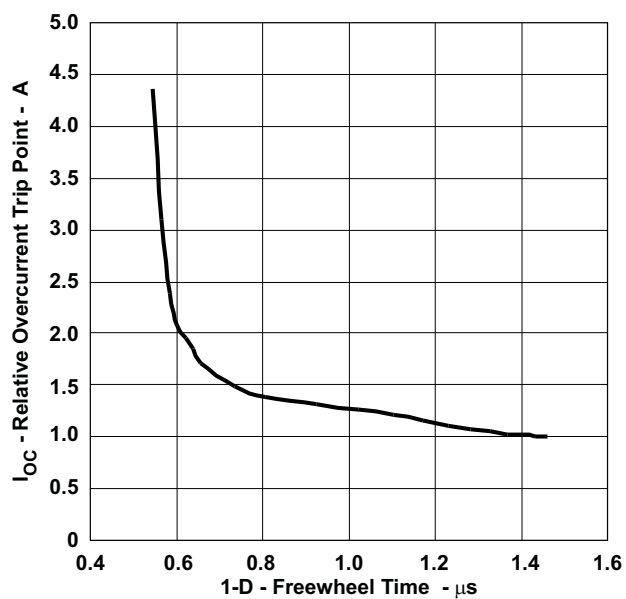
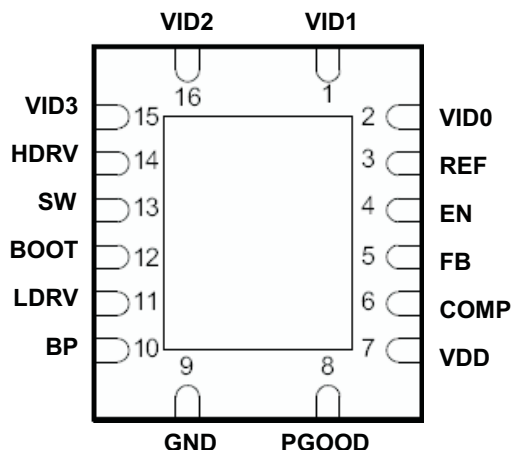


Figure 13.

DEVICE INFORMATION

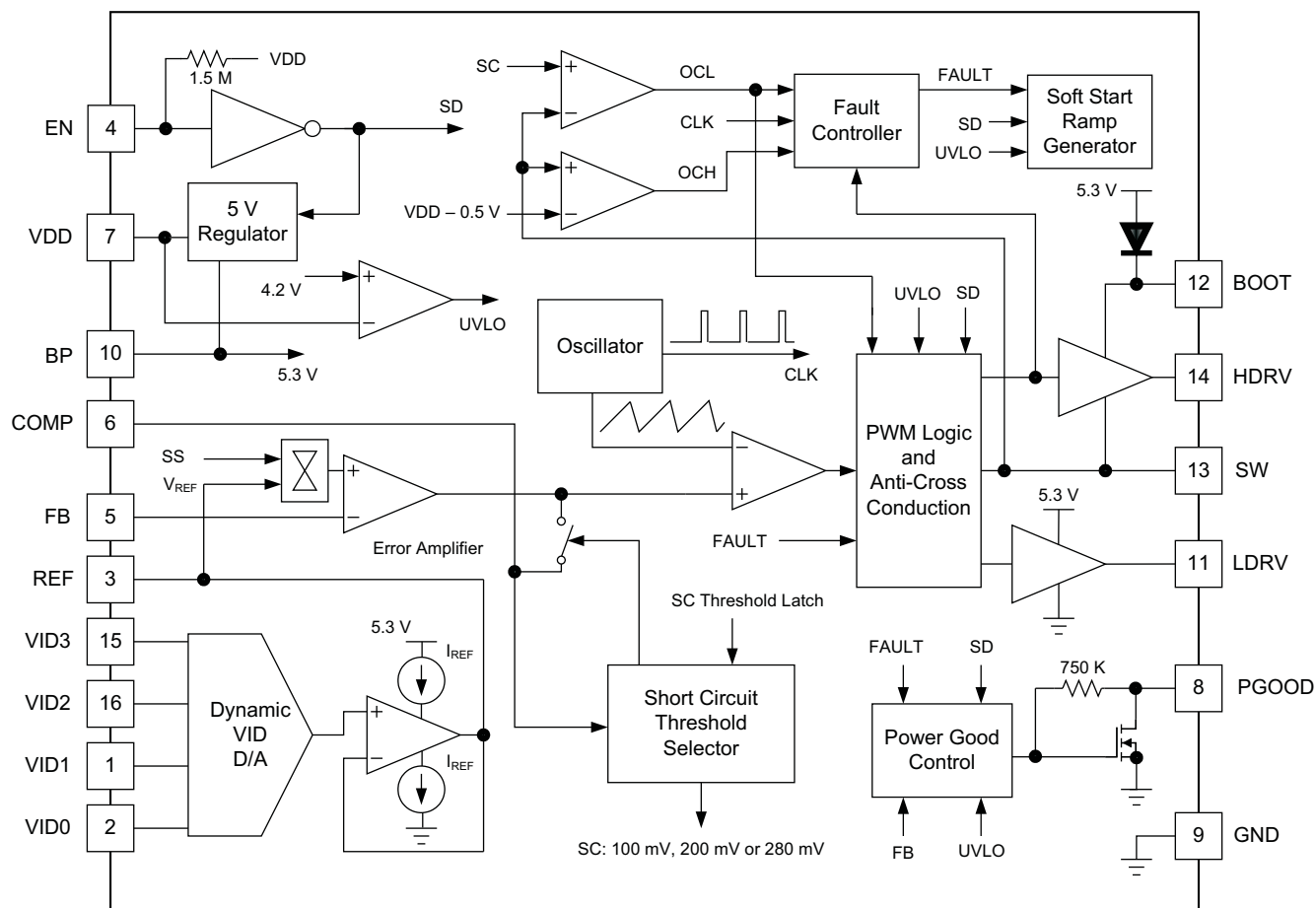
**Figure 14. RGY PACKAGE
(Bottom View)**



TERMINAL FUNCTIONS

TERMINAL		I/O	DESCRIPTION
NAME	NO.		
BOOT	12	I	Gate drive voltage for the high-side N-channel MOSFET. A 100-nF capacitor (typical) must be connected between this pin and SW.
BP	10	O	Output bypass for the internal regulator. Connect a low ESR bypass ceramic capacitor of 1 μ F or greater from this pin to GND.
COMP	6	O	Output of the error amplifier and connection node for loop feedback components.
EN	4	I	Logic level input which starts or stops the controller from an external user command. A high level turns the controller on. A weak internal pull-up holds this pin high so that the pin may be left floating if this function is not used. Pulling this pin low disables the controller.
FB	5	I	Inverting input to the error amplifier.
HDRV	14	O	Bootstrapped gate drive output for the high-side N-channel MOSFET.
LDRV	11	O	Gate drive output for the low-side synchronous rectifier N-channel MOSFET.
PGOOD	8	O	Open drain power good output.
REF	3	I	Non-Inverting input to the error amplifier. Its voltage range is from 0.9 V to 1.2 V in 20-mV steps. It is also internally connected to the DAC output through a unit gain buffer with 650- μ A source/sink current capability. An external capacitor connected from this pin to GND programs the output voltage transition rate when VID code changes.
VDD	7	I	Power input to the controller. A 1- μ F bypass capacitor should be connected closely from this pin to GND.
VID0	2	I	Logic level inputs to the internal DAC that provides the reference voltage for output regulation. These pins are internally pulled up to a 1.68-V source with 80- μ A pull-up current.
VID1	1	I	
VID2	16	I	
VID3	15	I	
GND	9		Ground connection to the controller

FUNCTIONAL BLOCK DIAGRAM



APPLICATION INFORMATION

Introduction

The TPS40197 is a synchronous buck controller which provides all the necessary features to construct a high-performance DC/DC converter. Support for pre-biased outputs eliminates concerns about damaging sensitive loads during startup. Strong gate drivers for the high-side and rectifier MOSFETs decrease switching losses for increased efficiency. Adaptive gate drive timing prevents shoot through and minimizes body diode conduction in the rectifier MOSFET, also increasing efficiency. Selectable short-circuit protection thresholds and hiccup recovery from a short-circuit increase design flexibility and minimize power dissipation in the event of a prolonged output fault. A dedicated enable pin allows the converter to be placed in a very low quiescent current shutdown mode. Internally fixed switching frequency and soft-start time reduce external component count, simplifying design and layout, as well as reducing footprint and cost. The dynamic voltage identification (VID) circuitry is designed to provide Smart-Reflex™ power supply solution to DSPs with core voltage optimization.

Enable

The TPS40197 includes a dedicated EN pin. This simplifies user level interface design since no multiplexed functions exist. Another benefit is a true low-power shutdown mode of operation. When the EN pin is pulled to GND, all unnecessary functions, including the BP regulator, are turned off, reducing the I_{VDD} current to 45 μ A. A functionally equivalent circuit of the enable circuitry is shown in Figure 15.

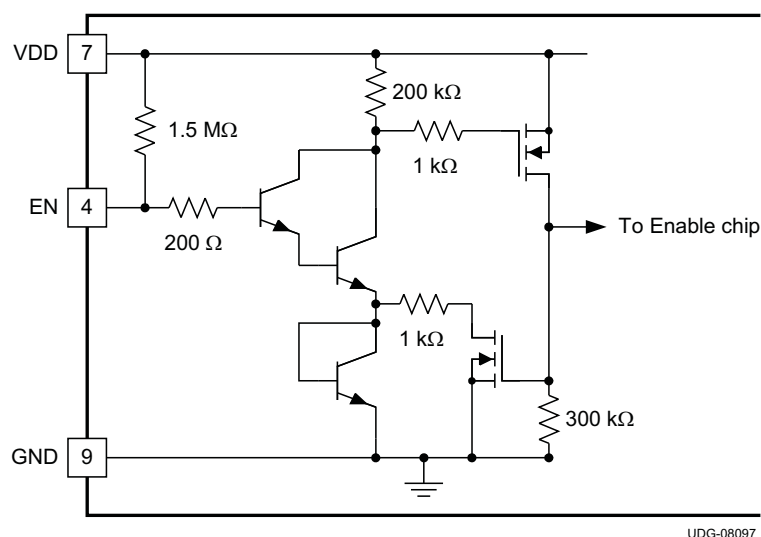


Figure 15. TPS40197 EN Pin Internal Circuitry

If the EN pin is left floating, the device starts automatically. The pin must be pulled to less than 600 mV to specify that the TPS40197 is in shutdown mode. Note that the EN pin is relatively high impedance. In some situations, there could be enough noise nearby to cause the EN pin to swing below the 600-mV threshold and give erroneous shutdown commands to other components of the device. There are two solutions to this potential problem.

- Place a capacitor from EN to GND. A side-effect of this is to delay the start of the converter while the capacitor charges past the enable threshold.
- Place a resistor from VDD to EN. This causes more current to flow in the shutdown mode, but does not delay converter startup. If a resistor is used, the total current into the EN pin should be limited to no more than 500 μ A.

The ENABLE pin is self-clamping. The clamp voltage can be as low as 1 V with a 1-k Ω ground impedance. Due to this self-clamping feature, the pull-up impedance on the ENABLE pin should be selected to limit the sink current to less than 500 μ A. Driving the ENABLE pin with a low-impedance source voltage can result in damage to the device. Because of the self-clamping feature, it requires care when connecting multiple ENABLE pins together. For enabling multiple TPS4019x devices (TPS40190, TPS40192, TPS40193, TPS40195, TPS40197), please refer to the Application Report [SLVA509](#).

Oscillator

The fixed internal switching frequency of the TPS40197 is 520 kHz.

UVLO

When the input voltage is below the UVLO threshold, the device holds all gate drive outputs in the low (OFF) state. When the input rises above the UVLO threshold, and the EN pin is above the turn ON threshold, the oscillator begins to operate and the start-up sequence is allowed to begin. The UVLO level is internally fixed at 4.2 V.

Startup Sequence and Timing

The TPS40197 startup sequence is as follows. After input power is applied, the 5-V onboard regulator initiates. Once this regulator comes up, the device goes through a period where it samples the impedance at the COMP pin and determines the short-circuit protection threshold voltage, by placing 400 mV on the COMP pin for approximately 1.15 ms. During this time, the current is measured and compared against internal thresholds to select the short circuit protection threshold. After this, the COMP pin is brought low for 1.15 ms. This ensures that the feedback loop is preconditioned at startup and no sudden output rise occurs at the output of the converter when the converter is allowed to start switching. After these initial 2.3 ms, the internal soft-start circuitry is engaged and the converter is allowed to start as shown in [Figure 16](#).

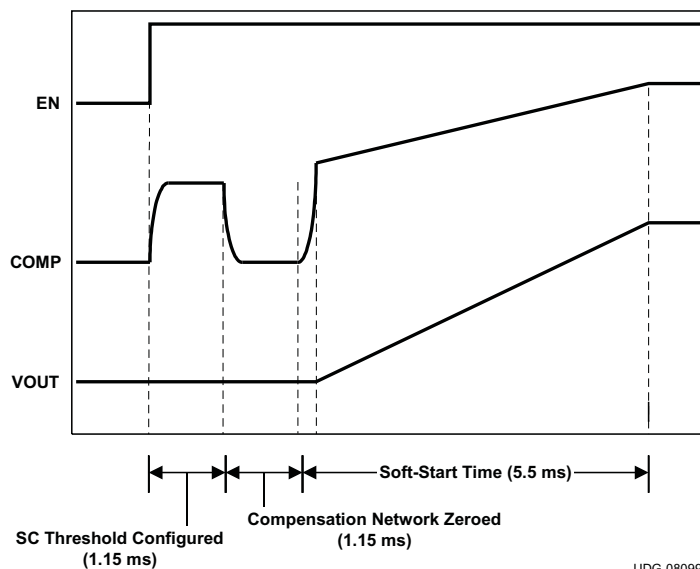


Figure 16. Startup Sequence

Selecting the Short Circuit Current

A short circuit in the TPS40197 is detected by sensing the voltage drop across the low-side FET when it is on, and across the high-side FET when it is on. If the voltage drop across either FET exceeds the short-circuit threshold in any given switching cycle, a counter increments one count. If the voltage across the high-side FET was higher than the short circuit threshold, that FET is turned off early. If the voltage drop across either FET does not exceed the short circuit threshold during a cycle, the counter is decremented for that cycle. If the counter fills up (a count of 7) a fault condition is declared and the drivers turn off both MOSFETs. After a timeout of approximately 50 ms, the controller attempts to restart. If a short circuit continues at the output, the current quickly ramps up to the short-circuit threshold and another fault condition is declared and the process of waiting for the 50 ms and attempting to restart repeats. The low-side threshold increases as the low-side on time decreases due to blanking time and comparator response time. See [Figure 13](#) for changes in the threshold as the low-side FET conduction time decreases.

The TPS40197 provides three selectable short-circuit protection thresholds for the low-side FET: 100 mV, 200 mV and 280 mV. The particular threshold is selected by connecting a resistor from COMP to GND. [Table 1](#) shows the short-circuit thresholds for corresponding resistors from COMP to GND. When designing the compensation for the feedback loop, remember that a low impedance compensation network combined with a long network time constant can cause the short-circuit threshold setting to not be as expected. The time constant and impedance of the network connected from COMP to FB should be as in [Equation 1](#) to ensure no interaction with the short-circuit threshold setting.

$$\left(\frac{0.4 \text{ V}}{R1} \right) \times e^{\left(\frac{-t}{R1 \times C1} \right)} \leq 10 \mu\text{A}$$

where

- t is 1.15 ms, the sampling time of the short circuit threshold setting circuit
- $R1$ and $C1$ are the values of the components in [Figure 17](#)

(1)

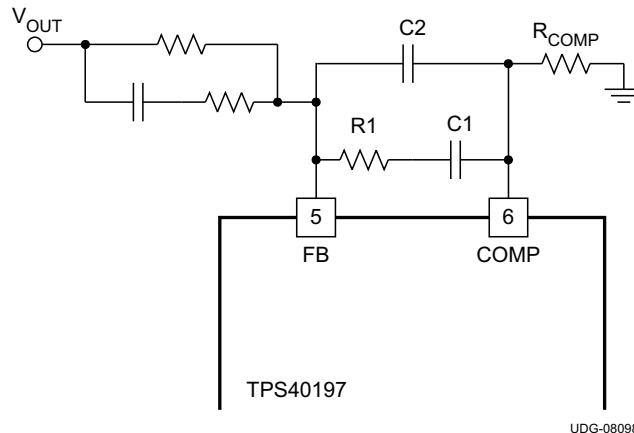


Figure 17. Short Circuit Threshold Feedback Network

Table 1. Circuit Threshold Voltage Selection

COMPARATOR RESISTANCE R_{COMP} (k Ω)	CURRENT LIMIT THRESHOLD VOLTAGE V_{ILIM} (mV)
12 \pm 10%	280
OPEN	200
4 \pm 10%	100

The range of expected short-circuit current thresholds is shown in [Equation 2](#) and [Equation 3](#).

$$I_{SCP(max)} = \frac{V_{ILIM(max)}}{R_{DS(on)min}} \quad (2)$$

$$I_{SCP(min)} = \frac{V_{ILIM(min)}}{R_{DS(on)max}}$$

where

- I_{SCP} is the short circuit current
- V_{ILIM} is the short-circuit threshold for the low-side MOSFET
- $R_{DS(on)}$ is the channel resistance of the low-side MOSFET

Note that due to blanking time considerations, overcurrent threshold accuracy may fall off for duty cycle greater than 75% because the overcurrent comparator has only a very short time to sample the SW pin voltage under these conditions and may not have time to respond to voltages very near the threshold.

The short-circuit protection threshold for the high-side MOSFET is fixed at 550 mV typical, 400 mV minimum. This threshold is in place to provide a maximum current output using pulse-by-pulse current limit in the case of a fault. The pulse terminates when the voltage drop across the high-side FET exceeds the short-circuit threshold. The maximum amount of current that can be specified to be sourced from a converter can be found by [Equation 4](#).

$$I_{OUT(max)} = \frac{V_{ILIMH(min)}}{R_{DS(on)max}}$$

where

- $I_{OUT(max)}$ is the maximum current that the converter is specified to source
- $V_{ILIMH(min)}$ is the short-circuit threshold for the high-side MOSFET (400 mV)
- $R_{DS(on)max}$ is the maximum resistance of the high-side MOSFET

If the required current from the converter is greater than the calculated $I_{OUT(max)}$, a lower resistance high-side MOSFET must be chosen. Both the high-side and low-side thresholds use temperature compensation to approximate the change in resistance for a typical power MOSFET. This helps counteract shifts in overcurrent thresholds as temperature increases. For this to be effective, the MOSFETs and the device must be well coupled thermally.

Voltage Reference and Dynamic VID

To provide optimized voltage for Smart-Reflex™ DSP cores, the TPS40197 is designed to monitor the VID code at all times once soft-start is complete, and actively adjusts its output voltage if the VID code should change during normal operation. A digital-to-analog converter (DAC) generates a reference voltage based on the state of logical signals at pins VID0 through VID3. The DAC decodes the 4-bit logic signal into one of the discrete voltages shown in [Table 2](#). The default setting for the output is 1.2 V (VID code 1111). The output voltage is 1.2 V during initial start or restart after cycling the input, toggling EN pin or recovering from a short circuit at the output.

To ensure that no erroneous output voltage is produced, the TPS40197 VID inputs have internal anti-skew circuit with approximately 550 ns of filtering time. Each VID input is pulled up to an internal 1.68-V source with 80-μA pull-up current for use with open-drain outputs.

The output voltage can be programmed from 0.9 V to 1.2 V in 20 mV steps. Smooth upward and downward core voltage transition can be achieved by programming the transition rate with an external capacitor connected from REF pin to GND. The required capacitance can be calculated using [Equation 5](#).

$$C_{REF} = \frac{(I_{REF} \times T_{TR})}{V_{VID-TR}}$$

where

- V_{VID-TR} is the total voltage transition through VID
- I_{REF} is the internal reference source/sink current
- T_{TR} is the intended total VID voltage transition time

(5)

C_{REF} must be limited to a maximum of 1.5 μF to avoid interfering with the soft-start. A capacitor (C_{REF}) with a minimum capacitance of 100-nF is also recommended.

Table 2. Voltage Identification Codes

VID TERMINALS (0 = LOW, 1 = HIGH)				V _{REF}
VID3	VID2	VID1	VID0	(V _{dc})
0	0	0	0	0.90
0	0	0	1	0.92
0	0	1	0	0.94
0	0	1	1	0.96
0	1	0	0	0.98
0	1	0	1	1.00
0	1	1	0	1.02
0	1	1	1	1.04
1	0	0	0	1.06
1	0	0	1	1.08
1	0	1	0	1.10
1	0	1	1	1.12
1	1	0	0	1.14
1	1	0	1	1.16
1	1	1	0	1.18
1	1	1	1	1.20

Minimum On-Time Consideration

The TPS40197 has a minimum on-time of 110 ns (maximum). With the restriction of this minimum on-time, the device may begin to skip pulses to effectively lower the overall on-time to keep the output in regulation when operating at high input-to-output conversion ratio. If pulse skipping is undesirable for some reason, it is recommended that the maximum input voltage be limited to 13.5 V.

BP Regulator

The TPS40197 has an on board 5-V BP regulator that allows the parts to operate from a single voltage feed. No separate 5-V feed to the part is required. This regulator needs to have a minimum of 1-μF of capacitance on the BP pin for stability. A ceramic capacitor is suggested for this purpose.

This regulator can also be used to supply power to nearby circuitry, eliminating the need for a separate LDO in some cases. If this pin is used for external loads, be aware that this is the power supply for the internals of the TPS40197. While efforts have been made to reduce sensitivity, any noise induced on this line has an adverse effect on the overall performance of the internal circuitry and shows up as increased pulse jitter, or skewed reference voltage. Also, when the device is disabled by pulling the EN pin low, this regulator is turned off and will not be available to supply power.

The amount of power available from this pin varies with the size of the power MOSFETs that the drivers must operate. Larger MOSFETs require more gate drive current and reduce the amount of power available on this pin for other tasks. The total current that can be drawn from this pin by both the gate drive and external loads cannot exceed 50 mA. The device itself consumes up to 4 mA from the regulator and the total gate drive current can be found from [Equation 6](#).

For regulator stability, a 1-μF capacitor is required to be connected from BP to GND. In some applications using higher gate charge MOSFETs, a larger capacitor is required for noise suppression. For a total gate charge of both the high-side and low-side MOSFETs greater than 20 nC, a 2.2-μF or larger capacitor is recommended.

$$I_G = f_{SW} \times (Q_{G(\text{high})} + Q_{G(\text{low})})$$

where

- I_G is the required gate drive current
 - f_{SW} is the switching frequency
 - $Q_{G(\text{high})}$ is the gate charge requirement for the high-side FET when $V_{GS} = 5 \text{ V}$
 - $Q_{G(\text{low})}$ is the gate charge requirement for the low-side FET when $V_{GS} = 5 \text{ V}$
- (6)

Pre-Bias Startup

The TPS40197 contains a unique circuit to prevent current from being pulled from the output during startup in the condition the output is pre-biased. When the soft-start commands a voltage higher than the pre-bias level (internal soft-start becomes greater than feedback voltage $[V_{FB}]$), the controller slowly activates synchronous rectification by starting the first LDRV pulse with a narrow on-time. It then increments that on-time on a cycle-by-cycle basis until it coincides with the time dictated by (1-D), where D is the duty cycle of the converter. This scheme prevents the initial sinking of the pre-bias output, and ensures that the output voltage (V_{OUT}) starts and ramps up smoothly into regulation and the control loop is given time to transition from pre-biased startup to normal mode operation with minimal disturbance to the output voltage. The amount of time from the start of switching until the low-side MOSFET is turned on for the full (1-D) interval is defined by 32 clock cycles.

Drivers

The drivers for the external HDRV and LDRV MOSFETs are capable of driving a gate-to-source voltage of 5 V. The LDRV driver switches between BP and GND, while HDRV driver is referenced to SW and switches between BOOT and SW. The drivers have non-overlapping timing that is governed by an adaptive delay circuit to minimize body diode conduction in the synchronous rectifier. The drivers are capable of driving MOSFETs that are appropriate for a 15-A converter.

Power Good

The TPS40197 provides an indication that output power is good for the converter. This is an open drain signal and pulls low when any condition exists that would indicate that the output of the supply might be out of regulation. These conditions include:

- V_{FB} is more than 10% from the reference voltage based on VID codes
- soft-start is active
- an undervoltage condition exists for the device
- a short-circuit condition has been detected
- die temperature is over (140°C)

NOTE

When there is no power to the device, PGOOD is not able to pull close to GND if an auxiliary supply is used for the power good indication. In this case, a built in resistor connected from drain to gate on the PGOOD pull down device makes the PGOOD pin look approximately like a diode to GND.

Thermal Shutdown

If the junction temperature of the device reaches the thermal shutdown limit of 140°C, the PWM and the oscillator are turned off and HDRV and LDRV are driven low, turning off both FETs. When the junction cools to the required level (120°C nominal), the PWM initiates soft-start as during a normal power-up cycle.

DESIGN EXAMPLE

This example illustrates a design for a 12 V to 0.9 V~1.2 V point-of-load synchronous buck converter. The design goal parameters are given in [Table 3](#).

Table 3. Design Goal Parameters

PARAMETER	TEST CONDITION	MIN	TYP	MAX	UNIT
V _{IN}	Input voltage	10.8		13.2	V
I _{IN}	Input current	I _{OUT} = 7 A, V _{IN} = 12 V		0.85	1
	No load input current	I _{OUT} = 0 A, V _{IN} = 12 V		35	50
V _{OUT}	Output voltage	I _{OUT} = 7 A, V _{IN} = 12 V		-1.50%	1.50%
	Line regulation	I _{OUT} = 7 A, 10.8 ≤ V _{IN} ≤ 13.2 V		0.50%	
	Load regulation	0 A ≤ I _{OUT} ≤ 7 A, V _{IN} = 12 V		0.50%	
V _{RIPPLE}	Output ripple	I _{OUT} = 7 A		24	mV
V _{TRANS}	Transient deviation	ΔI _{OUT} = 6 A @ 1 A/μs		24	mV
I _{OUT}	Output current	10.8 ≤ V _{IN} ≤ 13.2 V		0	7
f _{SW}	Switching frequency			520	kHz

The schematic for the design is shown in [Figure 18](#) and the list of materials is shown in [Table 4](#).

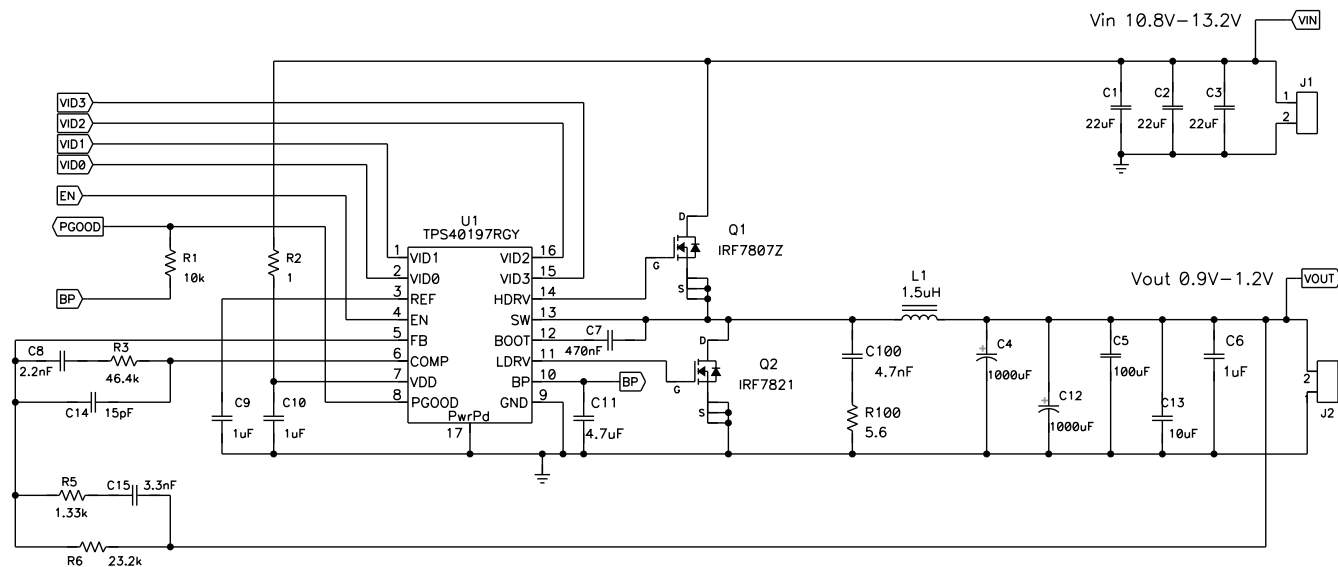


Figure 18. TPS40197 Sample Schematic

Table 4. Design Example List of Materials

REFERENCE DESIGNATOR	QTY	DESCRIPTION	MFR	PART NUMBER
C1, C2, C3	3	Capacitor, ceramic, 16 V, X7R, 20%, 22 μ F, 1210	TDK	C3225X7R1C226K
C4, C12	2	Capacitor, POSCAP, 2.5 V, 20%, 1 mF, 5 m Ω , D4D	Sanyo	2R5TPD1000M5
C5	1	Capacitor, ceramic, 6.3 V, X5R, 20%, 100 μ F, 1210	TDK	C3225X5R0J107K
C6, C9, C10	3	Capacitor, ceramic, 16 V, X7R, 20%, 1 μ F, 0603	Std	Std
C7	1	Capacitor, ceramic, 10 V, X5R, 20%, 470 nF, 0603	Std	Std
C8	1	Capacitor, ceramic, 50 V, NPO, 10%, 2.2 nF, 0603	Std	Std
C11	1	Capacitor, ceramic, 6.3 V, X5R, 20%, 4.7 μ F, 0603	TDK	C1608X5R0J475K
C13	1	Capacitor, ceramic, 6.3 V, X5R, 20%, 10 μ F, 0603	TDK	C1608X5R0J106K
C14	1	Capacitor, ceramic, 50 V, NPO, 10%, 15 pF, 0603	Std	Std
C15	1	Capacitor, ceramic, 50 V, X7R, 20%, 3.3 nF, 0603	Std	Std
C100	1	Capacitor, ceramic, 50 V, X7R, 20%, 4.7 nF, 0603	Std	Std
L1	1	Inductor, SMT, 27 A, 1.5 μ H, 2.5 m Ω , 0.508 x 0.520	Vishay	IHLP5050FDER1R5M01
Q1	1	MOSFET, N-channel, 30 V, 11A, 13.8 m Ω , SO-8	IR	IRF7807Z
Q2	1	MOSFET, N-channel, 30 V, 13.6 A, 9.1 m Ω , SO-8	IR	IRF7821
R1	1	Resistor, chip, 1/16 W, 5%, 10 k Ω , 0603	Std	Std
R2	1	Resistor, chip, 1/16 W, 5%, 1 Ω , 0603	Std	Std
R3	1	Resistor, chip, 1/16 W, 1%, 46.4 k Ω , 0603	Std	Std
R5	1	Resistor, chip, 1/16 W, 1%, 1.33 k Ω , 0603	Std	Std
R6	1	Resistor, chip, 1/16 W, 1%, 23.2 k Ω , 0603	Std	Std
R100	1	Resistor, chip, 1/4 W, 5%, 5.6 Ω , 1206	Std	Std
U1	1	IC, synchronous buck controller with 4-bit VID interface for Smart-Reflex DSPs, QFN-16	TI	TPS40197RGY

ADDITIONAL REFERENCES

RELATED DEVICES

The following devices have characteristics similar to the TPS40197 and may be of interest.

TI LITERATURE NUMBER	DEVICE	DESCRIPTION
SLUS719	TPS40192	4.5 V to 18 V Input Synchronous Buck Controller with Power Good
	TPS40193	

REFERENCES

TI LITERATURE NUMBER	DOCUMENT TYPE	DESCRIPTION
SPRAAW7	Application Report	TMS320C6474 Hardware Design Guide
SLVA057	Application Report	Understanding Buck Power Stages in Switchmode Power Supplies
SLUP206	Seminar Series	Under the Hood of Low-Voltage DC/DC Converters, SEM-1500, 2003
SLUP173	Seminar Series	Designing Stable Control Loops, SEM-1400, 2001
SLMA002	Application Report	PowerPAD™ Thermally Enhanced Package
SLMA004	Application Report	PowerPAD™ Made Easy

REVISION HISTORY

Changes from Original (November 2008) to Revision A	Page
<ul style="list-style-type: none"> Added a new paragraph to the Enable section 	12

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TPS40197RGYR	ACTIVE	VQFN	RGY	16	3000	Green (RoHS & no Sb/Br)	CU NIPDAU Call TI	Level-2-260C-1 YEAR	-40 to 85	40197	Samples
TPS40197RGYT	ACTIVE	VQFN	RGY	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU Call TI	Level-2-260C-1 YEAR	-40 to 85	40197	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBsolete: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION
REEL DIMENSIONS

TAPE DIMENSIONS


A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

TAPE AND REEL INFORMATION

*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS40197RGYR	VQFN	RGY	16	3000	330.0	12.4	3.8	4.3	1.5	8.0	12.0	Q1
TPS40197RGYT	VQFN	RGY	16	250	180.0	12.4	3.8	4.3	1.5	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS

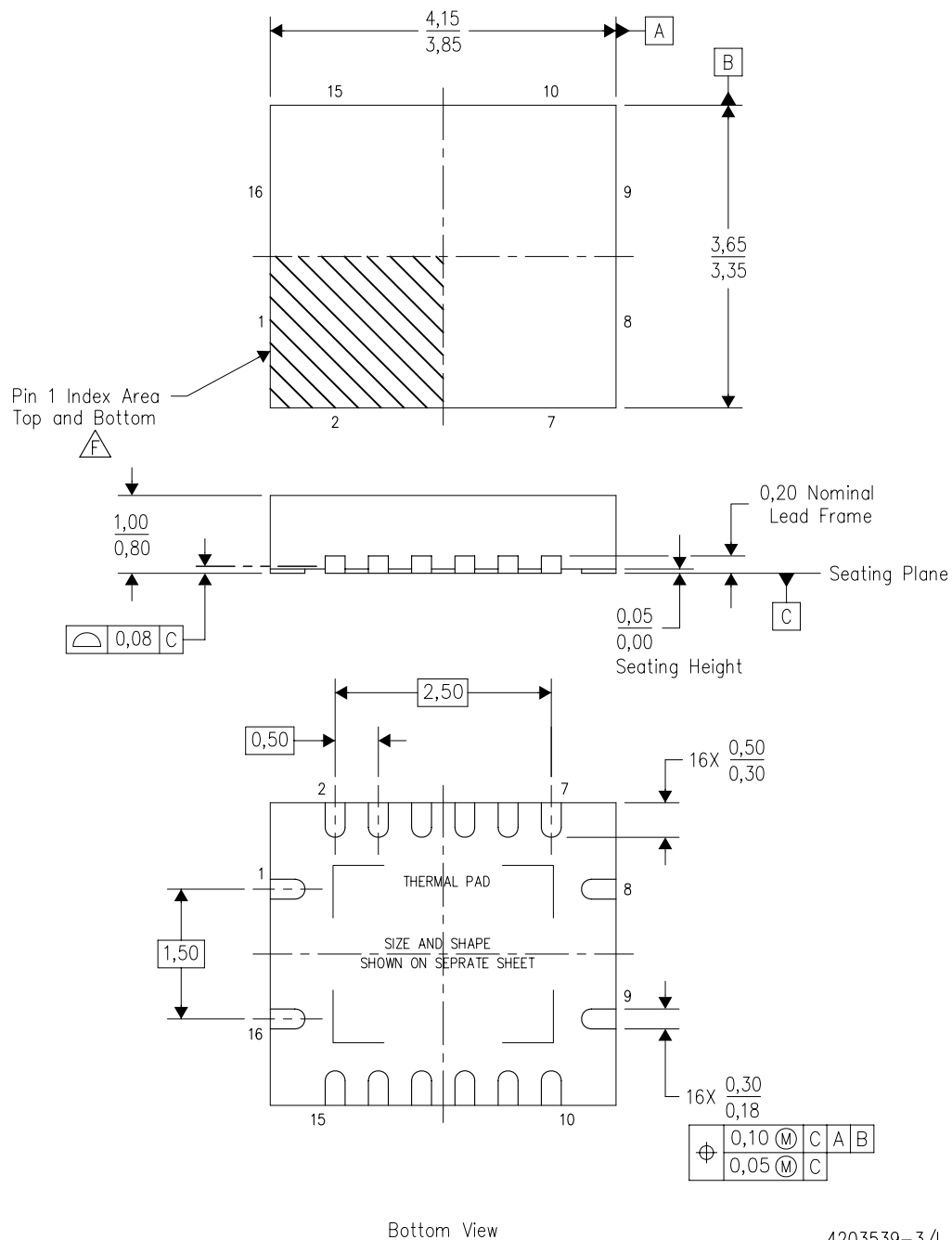


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS40197RGYR	VQFN	RGY	16	3000	367.0	367.0	35.0
TPS40197RGYT	VQFN	RGY	16	250	210.0	185.0	35.0

RGY (R-PVQFN-N16)

PLASTIC QUAD FLATPACK NO-LEAD



4203539-3/I 06/2011

- NOTES:
- All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
 - This drawing is subject to change without notice.
 - QFN (Quad Flatpack No-Lead) package configuration.
 - The package thermal pad must be soldered to the board for thermal and mechanical performance.
 - See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
- F** Pin 1 identifiers are located on both top and bottom of the package and within the zone indicated. The Pin 1 identifiers are either a molded, marked, or metal feature.
- Package complies to JEDEC MO-241 variation BA.

RGY (R-PVQFN-N16)

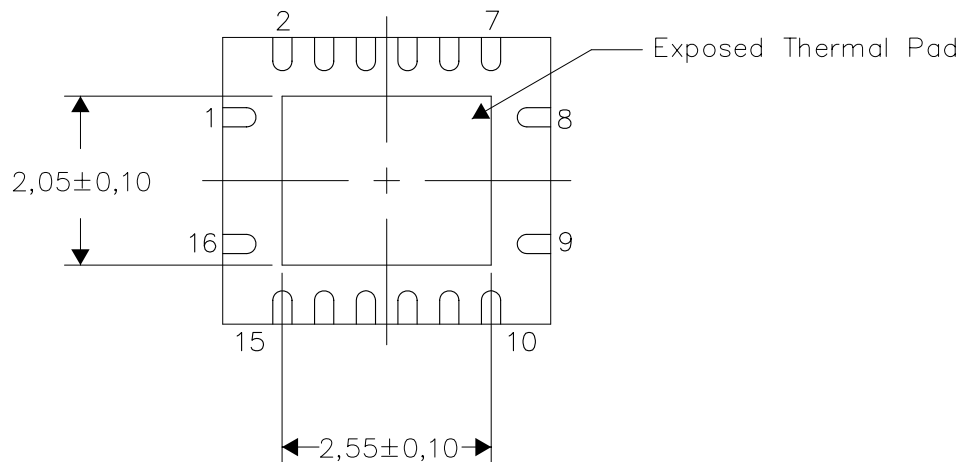
PLASTIC QUAD FLATPACK NO-LEAD

THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No-Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.

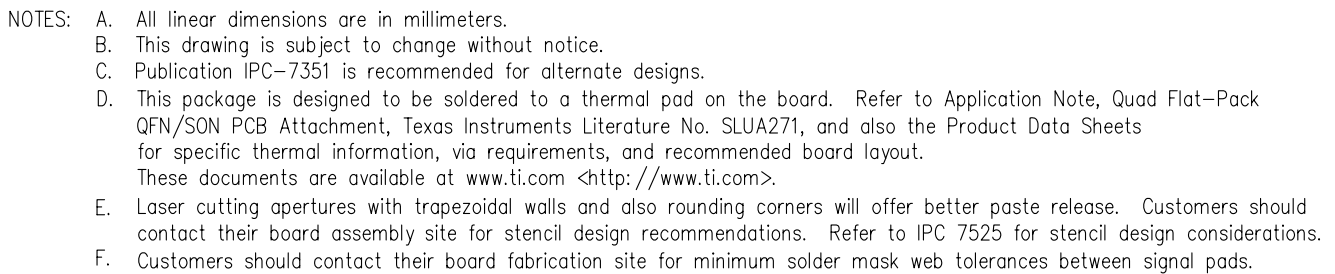


Bottom View

Exposed Thermal Pad Dimensions

4206353-3/0 11/11

NOTE: All linear dimensions are in millimeters



IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All semiconductor products (also referred to herein as "components") are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its components to the specifications applicable at the time of sale, in accordance with the warranty in TI's terms and conditions of sale of semiconductor products. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by applicable law, testing of all parameters of each component is not necessarily performed.

TI assumes no liability for applications assistance or the design of Buyers' products. Buyers are responsible for their products and applications using TI components. To minimize the risks associated with Buyers' products and applications, Buyers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI components or services are used. Information published by TI regarding third-party products or services does not constitute a license to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of significant portions of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI components or services with statements different from or beyond the parameters stated by TI for that component or service voids all express and any implied warranties for the associated TI component or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of TI components in its applications, notwithstanding any applications-related information or support that may be provided by TI. Buyer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences, lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Buyer will fully indemnify TI and its representatives against any damages arising out of the use of any TI components in safety-critical applications.

In some cases, TI components may be promoted specifically to facilitate safety-related applications. With such components, TI's goal is to help enable customers to design and create their own end-product solutions that meet applicable functional safety standards and requirements. Nonetheless, such components are subject to these terms.

No TI components are authorized for use in FDA Class III (or similar life-critical medical equipment) unless authorized officers of the parties have executed a special agreement specifically governing such use.

Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have **not** been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

Products

Audio	www.ti.com/audio
Amplifiers	amplifier.ti.com
Data Converters	dataconverter.ti.com
DLP® Products	www.dlp.com
DSP	dsp.ti.com
Clocks and Timers	www.ti.com/clocks
Interface	interface.ti.com
Logic	logic.ti.com
Power Mgmt	power.ti.com
Microcontrollers	microcontroller.ti.com
RFID	www.ti-rfid.com
OMAP Applications Processors	www.ti.com/omap
Wireless Connectivity	www.ti.com/wirelessconnectivity

Applications

Automotive and Transportation	www.ti.com/automotive
Communications and Telecom	www.ti.com/communications
Computers and Peripherals	www.ti.com/computers
Consumer Electronics	www.ti.com/consumer-apps
Energy and Lighting	www.ti.com/energy
Industrial	www.ti.com/industrial
Medical	www.ti.com/medical
Security	www.ti.com/security
Space, Avionics and Defense	www.ti.com/space-avionics-defense
Video and Imaging	www.ti.com/video

TI E2E Community

e2e.ti.com